RELIABILITY REPORT

FOR

MAX3885ECB

PLASTIC ENCAPSULATED DEVICES

January 29, 2003

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Written by

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Conclusion

The MAX3885 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX3885 deserializer is ideal for converting 2.488Gbps serial data to 16-bit wide, 155Mbps parallel data in SDH/SONET applications. Operating from a single +3.3V supply, this device accepts PECL serial clock and data inputs, and delivers low-voltage differential-signal (LVDS) clock and data outputs for interfacing with high-speed digital circuitry. It also provides an LVDS synchronization input that enables data realignment and reframing. The MAX3885 is available in the extended temperature range (-40°C to +85°C) in a 64-pin TQFP package.

B. Absolute Maximum Ratings

<u>ltem</u>	Rating
Positive Supply Voltage (VCC)	-0.5V to +7.0V
Input Voltage Level (all inputs)	-0.5V to (VCC + 0.5V)
Output Current LVDS outputs	10mA
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-60°C to +160°C
Lead Temperature (soldering, 10sec)	+300°C
Power Dissipation (TA = +85°C)	
64-Pin TQFP	1000mW
Derates above +85°C	
64-Pin TQFP	24mW/°C

II. Manufacturing Information

A. Description/Function: +3.3V, 2.488Gbps, SDH/SONET 1:16 Description with LVDS Outputs

B. Process: GST2 (High-Speed Double Poly-Silicon Bipolar Process)

C. Number of Device Transistors: 2820

D. Fabrication Location: Oregon, USA

E. Assembly Location: Malyasia

F. Date of Initial Production: July 1998

III. Packaging Information

A. Package Type: 64 Lead TQFP

B. Lead Frame: Copper

C. Lead Finish: Solder Plate

D. Die Attach: Silver-filled Epoxy

E. Bondwire: Gold (1.3 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: # 05-7001-0324

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-A112: Level 1

IV. Die Information

A. Dimensions: 97 x 101 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Poly / Au

D. Backside Metallization: None

E. Minimum Metal Width: 1.4 microns (as drawn)

F. Minimum Metal Spacing: 1.4 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO₂

I. Die Separation Method: Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts:

Jim Pedicord (Reliability Lab Manager)
Bryan Preeshl (Executive Director of QA)

Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 150°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 9823 \times 45 \times 2}$$
 (Chi square value for MTTF upper limit)

Thermal acceleration factor assuming a 0.8eV activation energy

 $\lambda = 10.78 \times 10^{-9}$ $\lambda = 10.78 \text{ F.I.T.}$ (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure the reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on lots exceeding this level. The following Burn-In Schematic (#06-6989) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors guarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress fom every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The HF06 die type has been found to have all pins able to withstand a transient pulse of ± 2000 V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ± 50 mA.

Table 1 Reliability Evaluation Test Results

MAX3885ECB

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Tes				_
	Ta = 150°C Biased	DC Parameters & functionality	45	0
	Time = 192 hrs. Junction Temperatur	·		
Moisture Testing (Note 2)				
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	77	0
Mechanical Str	ress (Note 2)			
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters	77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots. Note 2: Generic Package/Process Data

Attachment #1

TABLE II. Pin combination to be tested. 1/2/

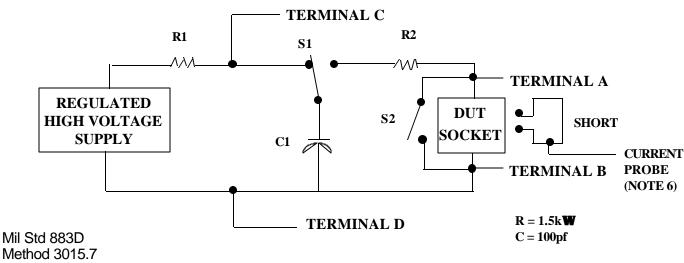
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V _{PS1} 3/	All V _{PS1} pins
2.	All input and output pins	All other input-output pins

- 1/ Table II is restated in narrative form in 3.4 below.
- No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_{S}$, $-V_{S}$, V_{REF} , etc).

3.4 Pin combinations to be tested.

- Each pin individually connected to terminal A with respect to the device ground pin(s) connected a. to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- Each pin individually connected to terminal A with respect to each different set of a combination b. of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- Each input and each output individually connected to terminal A with respect to a combination of C. all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Method 3015.7 Notice 8

